

DATASHEET

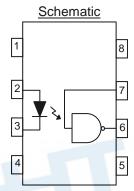
8 PIN DIP WIDE BODY HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER ELW137 ELW26XX Series





Features

- High speed 10Mbit/s
- Guaranteed performance from -40 to $85^\circ C$
- Logic gate output
- High isolation voltage between input and output (Viso =5000 V rms)
- Compliance with EU REACH
- The product itself will remain within RoHS compliant version
- UL and cUL approved(No. E214129)
- VDE approved (No. 40028391)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved



A 0.1µF bypass capacitor must be connected between pins 8 and 5 ^{*3}

Pin Configuration

- 1, No Connection
- 2, Anode
- 3, Cathode
- 4. No Connection
- 5, Gnd
- 6, Vout
- 7, V_E
- $8,\,V_{CC}$

Description

The ELW137, ELW2601 and ELW2611 consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output.

It is packaged in a 8-pin wide body package and available SMD options.

Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

Truth Table (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н

Absolute Maximum Ratings (T_A=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	50	mA
Input	Enable input voltage Not exceed V_{CC} by more than 500mV	V _E	5.5	V
input	Reverse voltage	V _R	5	V
	Power dissipation	P _D	100	mW
	Power dissipation	P _C	85	mW
0.1.1	Output current	Ι _Ο	l _o 50	
Output	Output voltage	Vo	7.0	V
	Supply voltage	V _{cc}	7.0	V
Isolation voltage *1		V _{ISO}	5000	V rms
Operating temperature		T _{OPR}	-40 ~ +85	°C
Storage temperature		T _{STG}	-55 ~ +125	°C
Soldering temperature *2		T _{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

*2 For 10 seconds.

Electrical Characteristics (T_A=-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V _F	-	1.4	1.8	V	I _F = 10mA
Reverse voltage	V _R	5.0	-	-	V	I_R = 100µA, T_A =25°C
Temperature coefficient of forward voltage	$\Delta V_{\rm F} / \Delta T_{\rm A}$	-	-1.9	-	mV/°C	I _F =10mA
Input capacitance	C _{IN}	-	70	-	pF	V _F =0, f=1MHz
Output Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
High level supply current	I _{CCH}	-	6.5	10	mA	$I_F=0mA$, $V_E=0.5V$, $V_{CC}=5.5V$
Low level supply current	I _{CCL}	-	8	13	mA	I_{F} =10mA, V_{E} =0.5V, V_{CC} =5.5V
High level enable current	I _{EH}	-	- 0.6	-1.6	mA	V_{E} =2.0V, V_{CC} =5.5V
Low level enable current	I _{EL}	-	- 0.8	-1.6	mA	V_{E} =0.5V, V_{CC} =5.5V
High level enable voltage	V_{EH}	2.0		-	V	I _F =10mA, V _{CC} =5.5V
Low level enable voltage ^{*4}	V _{EL}			0.8	V	I _F =10mA, V _{CC} =5.5V

Transfer Characteristics (T_A=-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
High level output current	I _{OH}	-	2.1	100	uA	V _{CC} =5.5V, V _O =5.5V, I _F =250uA, V _E =2.0V
Low level output voltage	V_{OL}	-	0.35	0.6	V	$V_{CC} = 5.5V$, I _F =5mA, V _E =2.0V, I _{OL} (Sinking)=13mA
Input threshold current	I_{FT}	-	3.0	5	mA	V_{CC} = 5.5V, V_{O} =0.6V, V_{E} =2.0V, I_{OL} (Sinking)=13mA

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Switching Characteristics (T_A=-40 to 85 $^{\circ}$ C, V_{CC}=5V, I_F=7.5mA unless specified otherwise)

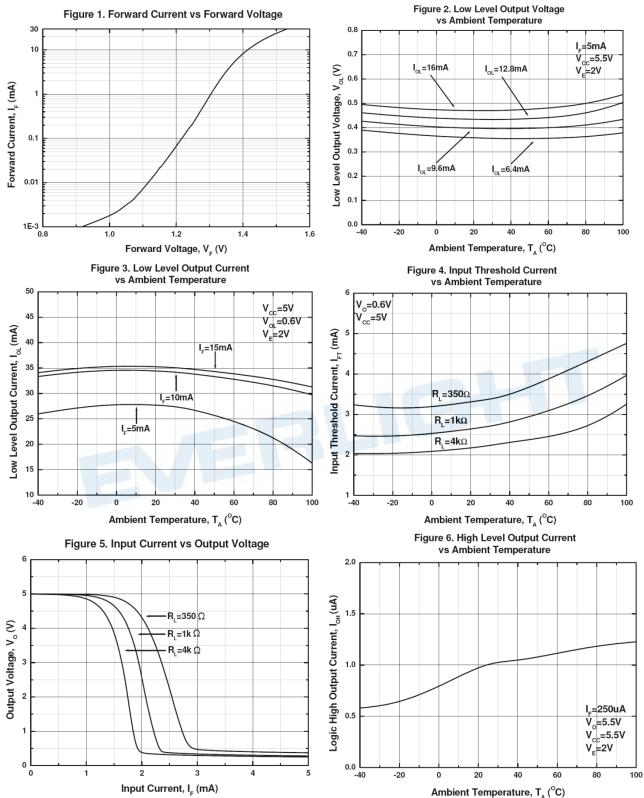
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Propagation delay time to output High level* ⁵ (Fig.12)	T _{PHL}	-	35	100	ns	C_L = 15pF, R_L =350 Ω , T_A =25 $^{\circ}C$
Propagation delay time to output Low level* ⁶ (Fig.12)	T _{PLH}	-	40	100	ns	C_L = 15pF, R_L =350 Ω , T_A =25 $^{\circ}$ C
Pulse width distortion	T _{PHL} I – T _{PLH}	-	5	40	ns	C_L = 15pF, R_L =350 Ω
Output rise time* ⁷ (Fig.12)	tr	-	40	-	ns	C_L = 15pF, R_L =350 Ω
Output fall time* ⁸ (Fig.12)	tf	-	10	-	ns	C_L = 15pF, R_L =350 Ω

Switching Characteristics (T_A=-40 to 85 $^{\circ}$ C, V_{CC}=5V, I_F=7.5mA unless specified otherwise)

Para	Parameter		Min	Тур.	Max.	Unit	Condition
Delay Time	Enable Propagation Delay Time to Output High Level ^{*9} (Fig.13)		-	15	-	ns	$I_F = 7.5 \text{mA}$, $V_{EH} = 3.5 \text{V}$, $C_L = 15 \text{pF}$, $R_L = 350 \Omega$
Enable Pro Delay Time Low Level* (Fig.13)	to Output	t _{EHL}	÷	15	1.	ns	$I_F = 7.5 \text{mA}$, $V_{EH} = 3.5 \text{V}$, $C_L = 15 \text{pF}$, $R_L = 350 \Omega$
	ELW137	Æ		1		V/µS	$I_F = 7.5 \text{mA}$, $V_{OH}=2.0 \text{V}$, $R_L=350 \Omega$, $T_A=25 ^{\circ} \text{C}$ $V_{CM}=10 \text{Vp-p}$ (Fig.14)
Common Mode Transient	ELW2601	- CM _H	5,000	-	-		$I_{F} = 7.5 \text{mA}, V_{OH}=2.0 \text{V},$ $R_{L}=350 \Omega, T_{A}=25 \degree C V_{CM}=50 \text{Vp-p}$ (Fig.14) $I_{F} = 7.5 \text{mA}, V_{OH}=2.0 \text{V},$ $R_{L}=350 \Omega, T_{A}=25 \degree C$ $V_{CM}=400 \text{Vp-p} \text{ (Fig.14)}$
Immunity at Logic High ¹¹	ELW2611		10,000	-	-		
	ELW2611		20,000	-	-		I _F = 7.5mA , V _{OH} =2.0V, R _L =350Ω, T _A =25℃ V _{CM} =400Vp-p (Fig.15)
Common	ELW137	CML	-	-	-	V/µS	I _F = 0mA , V _{OL} =0.8V, R _L =350Ω, T _A =25℃ V _{CM} =10Vp-p (Fig.14)
Common Mode	ELW2601		5,000	-	-		I _F = 0mA , V _{OL} =0.8V, R _L =350Ω, T _A =25℃ V _{CM} =50Vp-p (Fig.14)
Transient - Immunity	ELW2611		10,000	-	-		$I_F = 0mA$, $V_{OL} = 0.8V$, $R_L = 350\Omega$, $T_A = 25^{\circ}C$ $V_{CM} = 400Vp-p$ (Fig.14)
at Logic - Low ^{*12}	ELW2611		20,000	-	-		I _F = 7.5mA , V _{OH} =2.0V, R _L =350Ω, T _A =25℃ V _{CM} =400Vp-p (Fig.15)







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Figure 7. Propagation Delay vs. Forward Current 120 100 I_F=7.5mA V_{cc}=5V $V_{cc}=5V$ 90 100 R_=4kΩ(T_{PLH} 80 Propagation Delay, T_p (ns) Propagation Delay, T_p (ns) $R_{L}=4k\Omega(T_{PLH})$ 70 80 60 $R_{L}=4k\Omega$ 60 (T $R_{l} = 1 k\Omega$ $R_1 = 4k\Omega$ 50 $R_{L}=1k\Omega(T_{PLH})$ R_L=350Ω ∠R_L=1kΩ(T_{PHL}) R_L=1kΩ R_L=350Ω (T_{PF} 40 40 30 R,=350Ω(T_{PLH}) R_L=350Ω(T_{PLF} 20 ∟ -40 20 -20 80 0 20 40 60 100 5 6 8 9 10 11 12 13 14 15 7 Temperature, T_{A} (°C) Forward Current, I_F (mA) Figure 9. Pulse Width Distortion vs. Temperature Figure 10. Rise and Fall Time vs. Temperature 70 500 I_=7.5mA I_=7.5mA =5V 60 V_{cc}=5V Pulse Width Distortion, PWD (ns) 400 Rise and Fall Time, T_r / T_f (ns) $R_1 = 4k\Omega(T_r)$ 50 $\mathbf{R}_1 = 4\mathbf{k}\Omega$ 40 300 30 R_L=4kΩ R_L=1kΩ R_L=350Ω 200 R, =350Ω(T) (T) $R_1 = 1k\Omega(T_1)$ 20 R =350Ω $R_1 = 1k\Omega$ 100 10 0 0 -40 -20 0 20 40 60 80 100 -20 20 40 60 80 100 -40 0 Temperature, T_A (°C) Temperature, T_A (°C) Figure 11. Enable Propagation Delay vs. Temperature 120 100 Enable Propagation Delay, T_{E} (ns) $\mathbf{R}_{L} = 4\mathbf{k}\Omega(\mathbf{T}_{ELH})$ 80 R_L=4kΩ R_L=1kΩ R_L=350Ω 60 (T_{EHL}) R₁=1kΩ(T_{ELH}) R_L=350Ω(T_{ELH}) 40 20 ₀ L -40 -20 0 20 40 60 80 100

Temperature, T_A (°C)

Figure 8. Propagation Delay vs. Temperature

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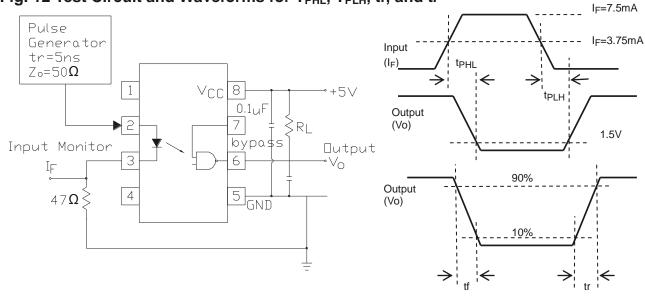


Fig. 12 Test Circuit and Waveforms for T_{PHL}, T_{PLH}, tr, and tf



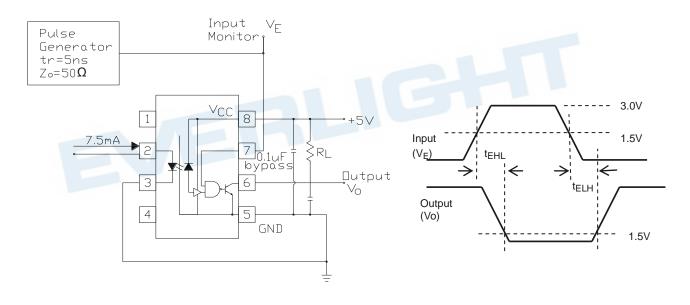




Fig. 14 Test Circuit Common Mode Transient Immunity

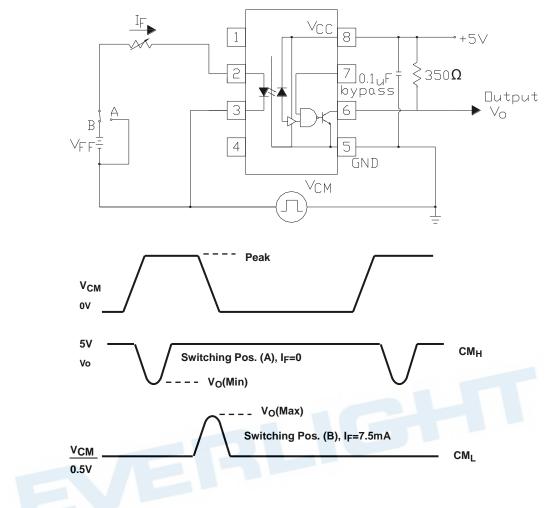
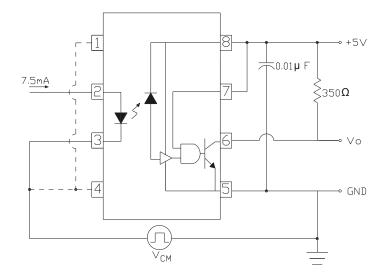


Fig. 15 Recommended Drive Circuit for ELW2611 Families for High-CMR



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Note

- *3 The V_{CC} supply must be bypassed by a 0.1µF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins
- *4. Enable Input No pull up resistor required as the device has an internal pull up resistor.
- *5. T_{PLH}– Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- *6. T_{PHL}– Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- *7. tr- Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- *8. tf- Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- *9. tELH– Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- *10. tEHL– Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- *11 CMH– The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., V_{OUT} > 2.0V).
- *12 CML– The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., V_{OUT} < 0.8V).

Order Information

Part Number

ELW137Y(Z)-V

Or

ELW26XXY(Z)-V

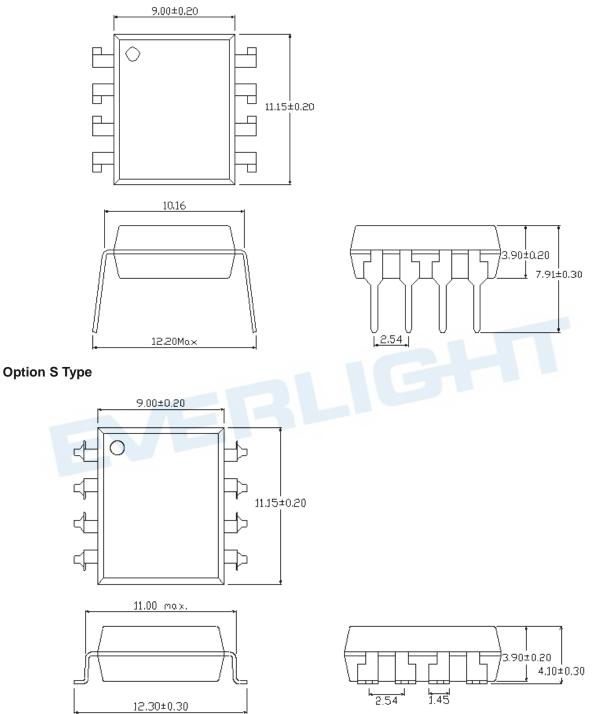
Note

- XX = 01 or 11 for ELW26 part no.
- Y = Lead form option (S or none)
- Z = Tape and reel option (TA, TB or none)
- V = VDE (optional)

Option	Description	Packing quantity
None	Standard DIP-8	40 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	500 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	500 units per reel

Package Dimension (Dimensions in mm)

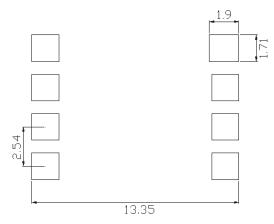
Standard DIP Type







Recommended Pad Layout for Surface Mount Leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

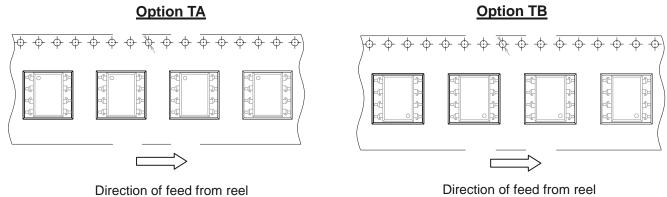


Notes

EL	denotes EVERLIGHT
W137	denotes Device Number
W2611	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

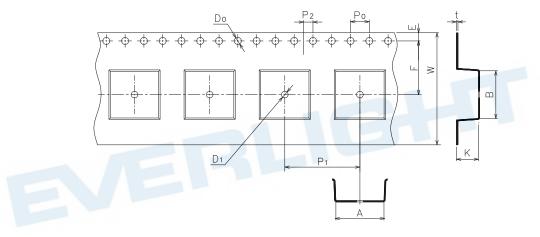


Tape & Reel Packing Specifications



Direction of feed from reel

Tape Dimension



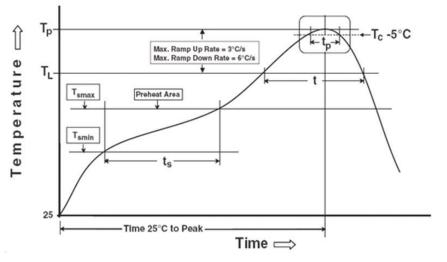
Dimension No.	Α	В	Do	D1	Е	F
Dimension(mm)	12.7±0.1	11.45±0.1	1.5±0.1	1.5±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	W	К
Dimension(mm)	4.0±0.1	16.0±0.1	2.0±0.1	0.4±0.05	24.00±0.3	4.6±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin})

Temperature max (T_{smax})

Time (T_{smin} to T_{smax}) (t_s) Average ramp-up rate (T_{smax} to T_p)

Other

Liquidus Temperature (T_L) Time above Liquidus Temperature (t_L) Peak Temperature (T_P) Time within 5°C of Actual Peak Temperature: T_P - 5°C Ramp- Down Rate from Peak Temperature Time 25°C to peak temperature Reflow times 150°C

Reference: IPC/JEDEC J-STD-020D

200°C 60-120 seconds 3°C/second max

217°C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

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